

100V PNP LOW SATURATION TRANSISTOR IN U-DFN2020-3

Features

- BVCE0 > -100V
- hFE Specified up to -3A for High Current Gain Hold Up
- Low Profile 0.6mm High Package for Thin Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts gualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

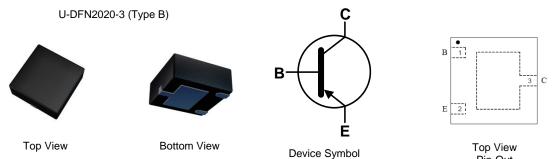
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: U-DFN2020-3 (Type B)
- Nominal Package Height: 0.6mm •
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.01 grams (Approximate)

Applications

- **DC-DC Converters**
- Charging Circuits
- Motor Control
- **Power Switches**



Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DXTP58100CFDB-7	2E6	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



2E6 = Product Type Marking Code YM = Date Code Marking Y = Y ear (ex: G = 2019)M = Month (ex: 9 = September)

Date Code Key

Year	2019		2020	2021		2022	2023		2024	2025		2026
Code	G		Н	I		J	K		L	М		Ν
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
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Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	Vсво	-100	
Collector-Emitter Voltage	Vceo	-100	V
Emitter-Base Voltage	Vebo	-7	
Peak Pulse Current	Ісм	-4	^
Continuous Collector Current	lc	-2	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D-	0.69	W	
	(Note 6)	PD	1.25	vv	
Thermal Resistance, Junction to Ambient	(Note 5)		180	°C/W	
	(Note 6)	R _{θJA}	100	C/VV	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

ESD Ratings (Note 7)

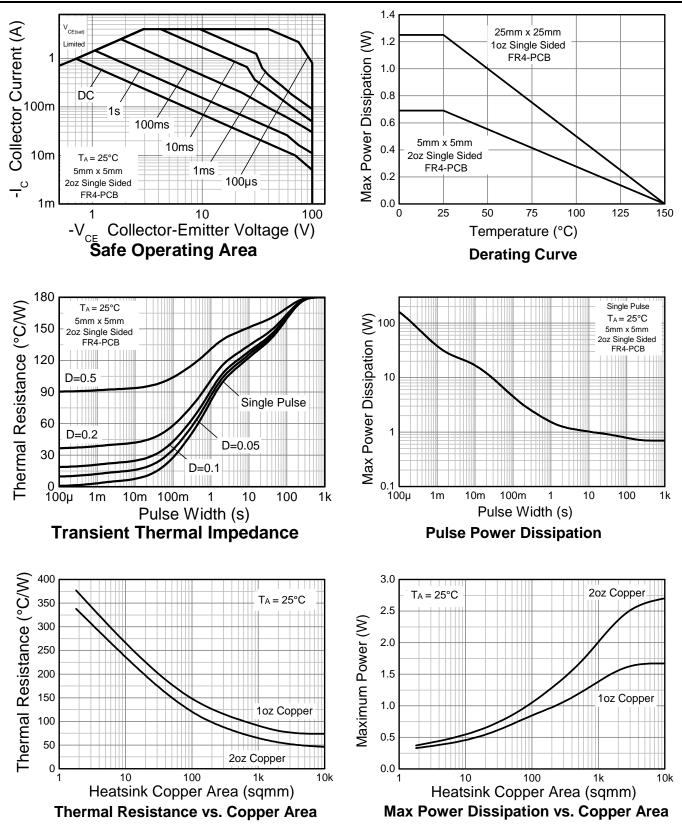
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the exposed collector on 5mm x 5mm 2oz copper on single sided FR4 PCB; device is measured under still air conditions whilst operating in the steady state.

6. Same as Note (5) except the exposed collector pad is mounted on 25mm x 25mm 1oz copper.
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





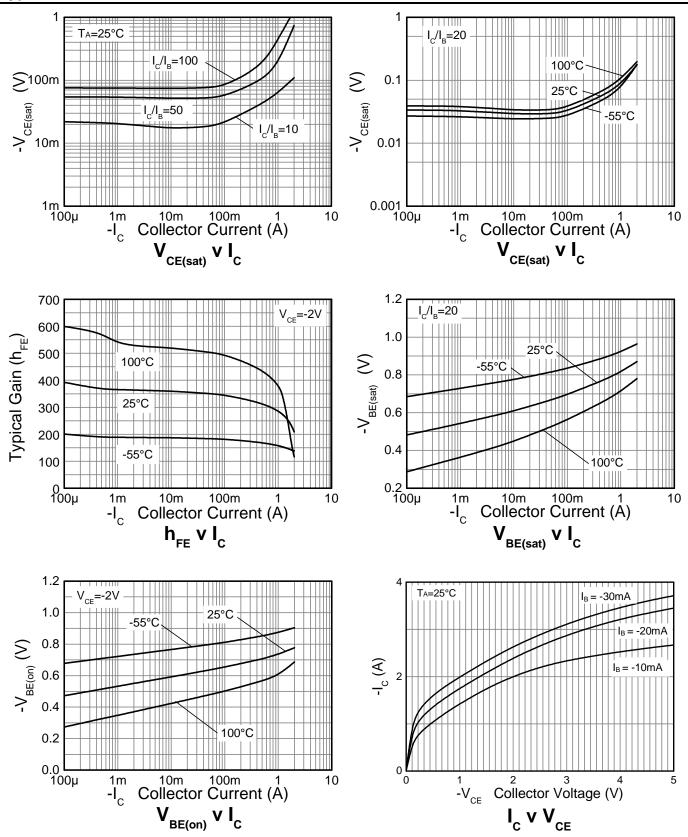
Electrical Characteristics (@T_A = +25°C, unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-100	_	_	V	Ic = -100μA
Collector-Emitter Breakdown Voltage (Note 8)	BVCEO	-100		—	V	Ic = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	_	_	V	I _E = -100μA
Collector Cutoff Current	Ісво	—	_	-100	nA	Vcb = -80V
Emitter Cutoff Current	IEBO	—	—	-100	nA	VEB = -6V
Collector Emitter Cutoff Current	ICES	—	_	-100	nA	V _{CES} = -80V
		160	260	—		Ic = -500mA, Vce = -2V
Static Forward Current Transfer Ratio (Note 8)	hfe	150	240	—		Ic = -1A, Vce = -2V
	NEE	90	180	—	_	$I_{C} = -2A$, $V_{CE} = -2V$
		15	60	—		IC = -3A, VCE = -2V
			-45	-70		Ic = -0.5A, I _B = -50mA
Collector-Emitter Saturation Voltage (Note 8)	VCE(sat)		-95	-150	mV	Ic = -1A, I _B = -50mA
		_	-125	-185		Ic = -2A, I _B = -200mA
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(on)}	—	-0.75	-0.9	V	$I_{C} = -2A, V_{CE} = -2V$
Base-Emitter Saturation Voltage (Note 8)	VBE(sat)	_	-0.75	-0.9	V	$I_{\rm C} = -1A, I_{\rm B} = -10mA$
Output Capacitance	Cobo	_	30		pF	V _{CB} = -10V, f = 1MHz
Transition Frequency	f⊤	—	135	_	MHz	Vce = -10V, Ic = -100mA, f = 100MHz
Delay Time	td	_	15	—		
Rise Time	tr	_	60		1	
Turn-On Time	ton	—	75	—		$V_{CC} = -9V, I_{C} = -2A$
Storage Time	ts	_	485	—	ns	IB1 = -IB2 = -0.1A
Fall Time	t _f	_	155	—		
Turn-Off Time	toff	_	640			

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

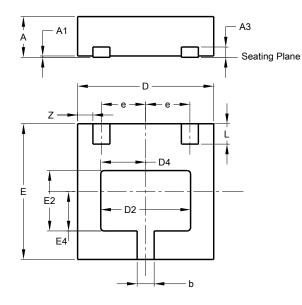




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

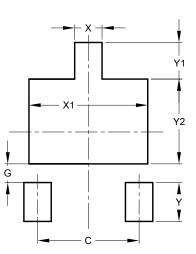
U-DFN2020-3 (Type B)



	U-DFN2020-3 (Type B)						
Dim	Min	Max	Тур				
Α	0.57	0.63	0.60				
A1	0.00	0.05	0.02				
A3			0.152				
b	0.20	0.30	0.25				
D	1.950	2.075	2.00				
D2	1.22	1.42	1.32				
D4	0.56	0.76	0.66				
E	1.950	2.075	2.00				
E2	0.79	0.99	0.89				
E4	0.48	0.68	0.58				
е	_	_	0.65				
L	0.25	0.35	0.30				
Z			0.225				
All	Dimens	ions in I	mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.300
G	0.240
Х	0.350
X1	1.520
Y	0.500
Y1	0.470
Y2	1.090

U-DFN2020-3 (Type B)



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